

LOW-VOLTAGE I/O TOUCH SCREEN CONTROLLER

Check for Samples: TSC2046E-Q1

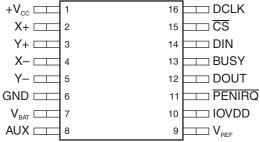
FEATURES

- Qualified for Automotive Applications
- Same Pinout as ADS7846
- 2.2-V to 5.25-V Operation
- 1.5-V to 5.25-V Digital I/O
- Internal 2.5-V Reference
- Direct Battery Measurement (0 V to 6 V)
- On-Chip Temperature Measurement
- Touch-Pressure Measurement
- QSPI[™] and SPI[™] 3-Wire Interface
- Auto Power-Down
- Exceeds IEC 61000-4-2 ESD Requirements
 - ±15kV Contact Discharge
 - No External Components Needed
- Available In a TSSOP-16 (PW) Package

APPLICATIONS

Touch Screen Monitors

PW PACKAGE (TOP VIEW)



DESCRIPTION

The TSC2046E is the next-generation version of the ADS7846 4-wire touch screen controller, supporting a low-voltage I/O interface from 1.5 V to 5.25 V. The TSC2046E is 100% pin-compatible with the existing ADS7846, and drops into the same socket. This design allows for an easy upgrade of current applications to the new version. The TSC2046E also has an on-chip 2.5-V reference that can be used for the auxiliary input, battery monitor, and temperature measurement modes. The reference can also be powered down when not used to conserve power. The internal reference operates down to a supply voltage of 2.7 V, while monitoring the battery voltage from 0 V to 6 V.

The low power consumption of less than 0.75 mW (typ) at 2.7 V (reference off), high-speed (up to 125-kHz sample rate), and on-chip drivers make the TSC2046E an ideal choice for battery-operated systems such as personal digital assistants (PDAs) with resistive touch screens, pagers, cellular phones, and other portable equipment. The TSC2046E is available in a TSSOP-16 package and is specified over the -40°C to +125°C temperature range.

ORDERING INFORMATION(1)

T _A		PACKAGE	ORDERABLE P	ART NUMBER TOP-SIDE MARKING
-40°C to 125°	C TSSOP - P	W Reel of 2	TSC2046EQPWR	Q1 T2046EQ

(1) For the most current package and ordering information, see the Package Option Addendum at the end of this document, or see the TI web site at www.ti.com.



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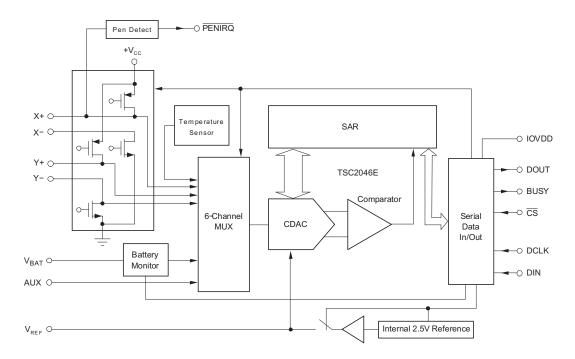
TEXAS INSTRUMENTS

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This integrated circuit can be damaged by ESD. Texas Instruments recommends that all integrated circuits be handled with appropriate precautions. Failure to observe proper handling and installation procedures can cause damage.

ESD damage can range from subtle performance degradation to complete device failure. Precision integrated circuits may be more susceptible to damage because very small parametric changes could cause the device not to meet its published specifications.



TERMINAL FUNCTIONS

TERMI	NAL	DESCRIPTION
NAME	NO.	DESCRIPTION
+V _{CC}	1	Power supply
X+	2	X+ position input
Y+	3	Y+ position input
X-	4	X- position input
Y-	5	Y- position input
GND	6	Ground
V_{BAT}	7	Battery monitor input
AUX	8	Auxiliary input to ADC
V_{REF}	9	Voltage reference input/output
IOVDD	10	Digital I/O power supply
PENIRQ	11	Pen interrupt
DOUT	12	Serial data output. Data are shifted on the falling edge of DCLK. This output is high impedance when $\overline{\text{CS}}$ is high.
BUSY	13	Busy output. This output is high impedance when $\overline{\text{CS}}$ is high.
DIN	14	Serial data input. If CS is low, data sre latched on the rising edge of DCLK.
CS	15	Chip select input. Controls conversion timing and enables the serial input/output register. Shigh = power-down mode (ADC only).
DCLK	16	External clock input. This clock runs the SAR conversion process and synchronizes serial data I/O.

ABSOLUTE MAXIMUM RATINGS(1) (2)

over operating free-air temperature range (unless otherwise noted)

V_{CC}	Supply voltage range	+V _{CC} , IOVDD	-0.3 V to 6 V		
\/	Input voltage range	Digital inputs	-0.3 V to +V _{CC} + 0.3 V		
VI	Input voltage range	Analog inputs	-0.3 V to +V _{CC} + 0.3 V		
P_{D}	Power dissipation	250 mW			
θ_{JA}	Package thermal impedance, junction to fr	108.4°C			
T_A	Operating free-air temperature range		-40°C to 125°C		
T_{J}	Maximum junction temperature		150°C		
T _{stg}	Storage temperature range	Storage temperature range			
	IEC Contact Discharge (3)	±15kV			

⁽¹⁾ Stresses beyond those listed under absolute maximum ratings may cause permanent damage to the device. These are stress ratings only, and functional operation of the device at these or any other conditions beyond those indicated under recommended operating conditions is not implied. Exposure to absolute-maximum-rated conditions for extended periods may affect device reliability.

ELECTRICAL CHARACTERISTICS

 T_A = -40°C to 125°C, +V_{CC} = 2.7V, V_{REF} = 2.5V internal voltage, f_{SAMPLE} = 125kHz, f_{CLK} = 16 × f_{SAMPLE} = 2MHz, 12-bit mode, digital inputs = GND or IOVDD, +V_{CC} \geq IOVDD (unless otherwise noted)

	PARAMETER	TEST CONDITIONS	MIN	TYP	MAX	UNIT
Analog	Input		1			
VI	Full-scale input voltage span	Positive Input-Negative Input	0		V_{REF}	V
\/	Alexander in a control to a con	Positive Input	-0.2		+V _{CC} + 0.2	V
VI	Absolute input voltage	Negative Input	-0.2		+0.2	V
C _i	Capacitance			25		pF
I _{leak}	Leakage current			0.1		μΑ
System	Performance	•	•			•
	Resolution			12		bits
	No missing codes		11			bits
	Integral linearity error				±2	LSB ⁽¹⁾
	Offset error				±6	LSB
	Gain error	External V _{REF}			±4	LSB
V _n	Noise	Including internal V _{REF} , RMS		70		μV
PSRR	Power-supply rejection ratio			70		dB
Samplin	ng Dynamics					
	Conversion time				12	CLK cycles
	Acquisition time		3			CLK cycles
	Throughput rate				125	kHz
	Multiplexer settling time			500		ns
	Aperture delay			30		ns
	Aperture jitter			100		ns
	Channel-to-channel isolation	$V_{IN} = 2.5 V_{pp}$ at 50 kHz		100		dB
Switch I	Drivers					
	Y+, X+ on-resistance			5		Ω
	Y-, X- on-resistance			6		Ω
	Drive current ⁽²⁾	Duration 100 ms			50	mA

¹⁾ LSB = least significant bit. With V_{REF} equal to 2.5 V, one LSB is 610 μ V.

²⁾ All voltages are referenced to GND.

⁽³⁾ Test method based on IEC Std 61000-4-2. Contact Texas Instruments for test details.

²⁾ Specified by design. Exceeding 50-mA source current may result in device degradation.

ELECTRICAL CHARACTERISTICS (continued)

 $T_A = -40^{\circ}\text{C}$ to 125°C, $+V_{CC} = 2.7\text{V}$, $V_{REF} = 2.5\text{V}$ internal voltage, $f_{SAMPLE} = 125\text{kHz}$, $f_{CLK} = 16 \times f_{SAMPLE} = 2\text{MHz}$, 12-bit mode, digital inputs = GND or IOVDD, $+V_{CC} \ge \text{IOVDD}$ (unless otherwise noted)

	PARAMETER	TEST CONDITIONS	MIN	TYP	MAX	UNIT		
Reference	e Output							
	Internal reference voltage		2.45	2.50	2.55	V		
	Internal reference drift			15		ppm/ °C		
IQ	Quiescent current	PD1 = 1, PD0 = 0, SDA and SCL high		500		μΑ		
Reference	ce Input							
VI	Input voltage		1		+V _{CC}	V		
	Innut impedance	$SER/\overline{DFR} = 0$, PD1 = 0, Internal reference off		1		GΩ		
	Input impedance	Internal reference on		250		Ω		
Battery I	Monitor							
VI	Input voltage		0.5		6	V		
7	land in a dece	Sampling battery		10		kΩ		
Z _I	Input impedance	Battery monitor off		1		GΩ		
	A	V _{BAT} = 0.5 V to 5.5 V, External V _{REF} = 2.5 V	-2		+2	0/		
	Accuracy	V _{BAT} = 0.5 V to 5.5 V, Internal reference	-3		+3	%		
Tempera	ture Measurement							
	Temperature range		-40		125	°C		
	B 1 ii	Differential method ⁽³⁾		1.6				
	Resolution	TEMP0 ⁽⁴⁾		0.3		°C		
	•	Differential method ⁽³⁾		±2				
	Accuracy	TEMP0 ⁽⁴⁾		±3		°C		
Digital In	put/Output							
V _{IH}	High-level input voltage	I _{IH} ≤ 5 μA	0.7 x IOVDD		IOVDD + 0.3	V		
V_{IL}	Low-level input voltage	I _{IL} ≤ 5 µA	-0.3		0.3 × IOVDD	V		
V_{OH}	High-level output voltage	I _{OH} = -250 μA	0.8 × IOVDD			V		
V_{OL}	Low-level output voltage	$I_{OL} = 250 \mu A$			0.4	V		
Ci	Input capacitance	All digital control input pins		5	15	pF		
Power S	upply Requirements							
±\/a	Supply voltage ⁽⁵⁾	Specified performance	2.7		3.6	V		
+V _{CC}		Operating range	2.5		5.25	V		
IOVDD	Supply voltage (6)		1.5		+V _{CC}	V		
		Internal reference off		280	650			
	Quicecent ourrent	Internal reference on		970		^		
lQ	Quiescent current	f _{SAMPLE} = 12.5 kHz		220	.	μΑ		
		Power-down mode, \overline{CS} = DCLK = DIN = IOVDD		10	28	3		
P _D	Power dissipation	+V _{CC} = 2.7 V			1.8	mW		
Tempera	ture Range							
T _A	Operating free-air temperature	Specified performance	-40		125	°C		
		•						

Difference between TEMP0 and TEMP1 measurement. No calibration necessary.

Temperature drift is -2.1 mV/°C.s

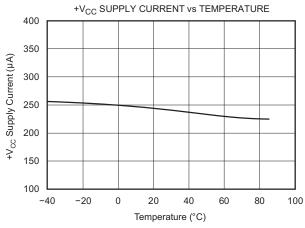
⁽⁵⁾ (6) TSC2046E operates down to 2.2V.

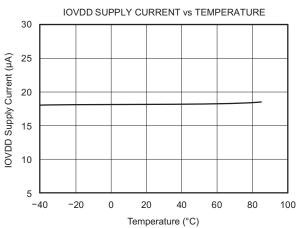
IOVDD must be $\leq +V_{CC}$.

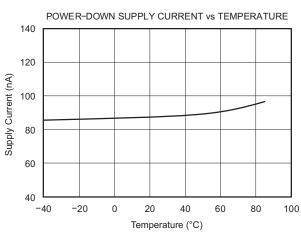
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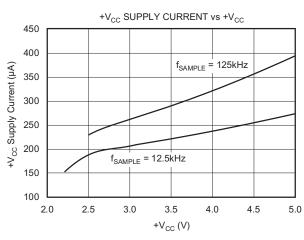
TYPICAL CHARACTERISTICS

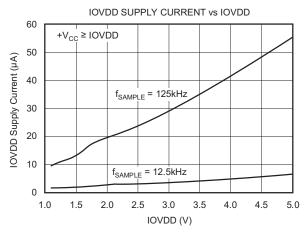
 $\text{At T}_{\text{A}} = +25 ^{\circ}\text{C}, \ +\text{V}_{\text{CC}} = +2.7 \text{V}, \ \text{IOVDD} = +1.8 \text{V}, \ \text{V}_{\text{REF}} = \text{External } +2.5 \text{V}, \ 12\text{-bit mode}, \ \text{PD0} = 0, \ \text{f}_{\text{SAMPLE}} = 125 \text{kHz}, \\ \text{f}_{\text{CLK}} = 16 \times \text{f}_{\text{SAMPLE}} = 2 \text{MHz} \ \text{(unless otherwise noted)}$

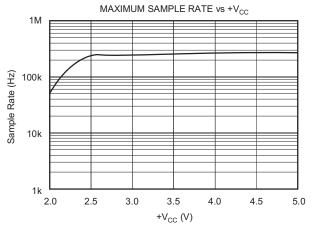








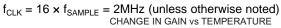


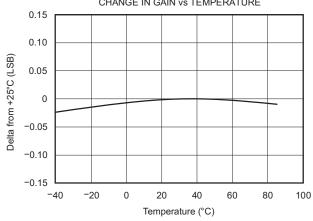


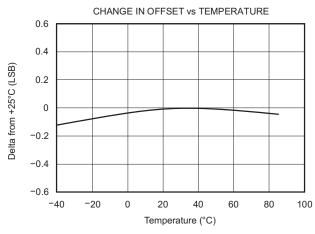


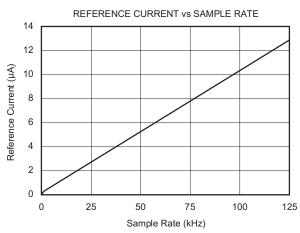
TYPICAL CHARACTERISTICS (continued)

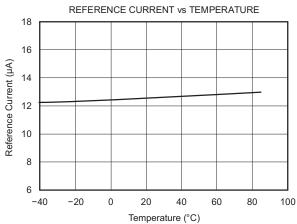
At $T_A = +25^{\circ}C$, $+V_{CC} = +2.7V$, IOVDD = +1.8V, $V_{REF} = External +2.5V$, 12-bit mode, PD0 = 0, $f_{SAMPLE} = 125kHz$,

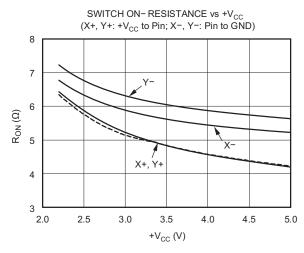


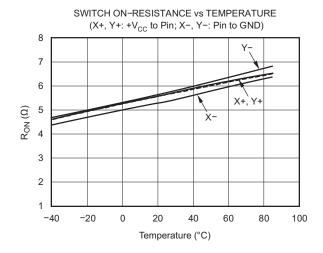








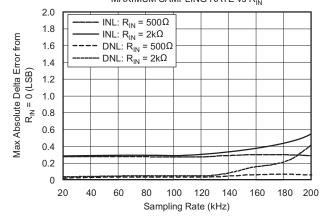


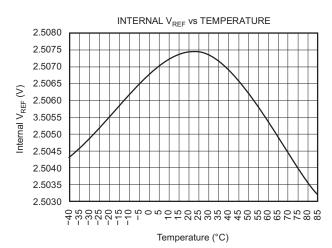


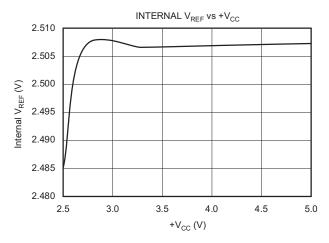
TYPICAL CHARACTERISTICS (continued)

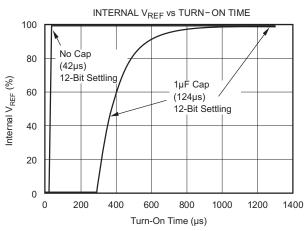
At $T_A = +25$ °C, $+V_{CC} = +2.7$ V, IOVDD = +1.8V, $V_{REF} = External +2.5$ V, 12-bit mode, PD0 = 0, $f_{SAMPLE} = 125$ kHz,

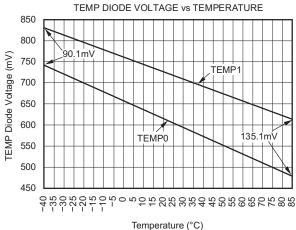
 f_{CLK} = 16 × f_{SAMPLE} = 2MHz (unless otherwise noted) MAXIMUM SAMPLING RATE vs R_{IN}

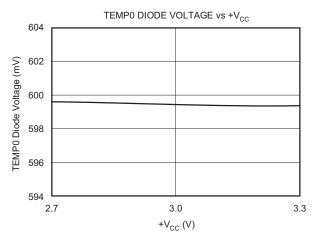






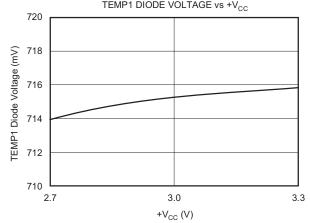






TYPICAL CHARACTERISTICS (continued)

At T_A = +25°C, +V_{CC} = +2.7V, IOVDD = +1.8V, V_{REF} = External +2.5V, 12-bit mode, PD0 = 0, f_{SAMPLE} = 125kHz, f_{CLK} = 16 × f_{SAMPLE} = 2MHz (unless otherwise noted) TEMP1 DIODE VOLTAGE vs +V_{CC}



THEORY OF OPERATION

The TSC2046E is a classic successive approximation register (SAR) analog-to-digital converter (ADC). The architecture is based on capacitive redistribution, which inherently includes a sample-and-hold function. The converter is fabricated on a 0.6µm CMOS process.

The basic operation of the TSC2046E is shown in Figure 1. The device features an internal 2.5-V reference and an internal clock. Operation is maintained from a single supply of 2.7 V to 5.25 V. The internal reference can be overdriven with an external, low-impedance source between 2 V and +V_{CC}. The value of the reference voltage directly sets the input range of the converter.

The analog input (X-, Y-, and Z-position coordinates, auxiliary inputs, battery voltage, and chip temperature) to the converter is provided via a multiplexer. A unique configuration of low on-resistance switches allows an unselected ADC input channel to provide power and an accompanying pin to provide ground for an external device. By maintaining a differential input to the converter and a differential reference architecture, it is possible to negate the error from each touch panel driver switch on-resistance (if this is a source of error for the particular measurement).

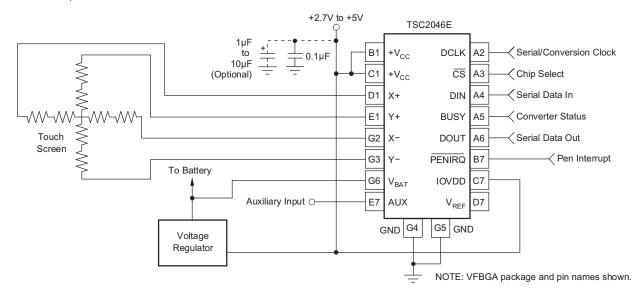


Figure 1. Basic Operation

Analog Input

Figure 2 shows a block diagram of the input multiplexer on the TSC2046E, the differential input of the ADC, and the differential reference of the converter. Table 1 and Table 2 show the relationship between the A2, A1, A0, and SER/DFR control bits and the configuration of the TSC2046E. The control bits are provided serially via the DIN pin—see the Digital Interface section of this data sheet for more details.

When the converter enters the Hold mode, the voltage difference between the +IN and -IN inputs (see Figure 2) is captured on the internal capacitor array. The input current on the analog inputs depends on the conversion rate of the device. During the sample period, the source must charge the internal sampling capacitor (typically 25 pF). After the capacitor has been fully charged, there is no further input current. The amount of charge transfer from the analog source to the converter is a function of conversion rate.

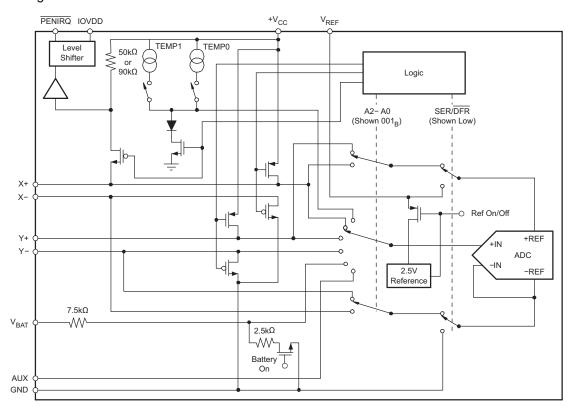


Figure 2. Simplified Diagram of the Analog Input

Table 1. Input Configuration (DIN), Single-Ended Reference Mode (SER/DFR High)

A2	A 1	A0	V _{BAT}	AUX _{IN}	Temp	Y-	X+	Y+	Y- Position	X- Position	Z ₁ - Position	Z ₂ - Position	X- Drivers	Y- Drivers
0	0	0			+IN (TEMP0)								Off	Off
0	0	1					+IN		Measure				Off	On
0	1	0	+IN										Off	Off
0	1	1					+IN				Measure		X-, On	Y+, On
1	0	0				+IN						Measure	X-, On	Y+, On
1	0	1						+IN		Measure			On	Off
1	1	0		+IN									Off	Off
1	1	1			+IN (TEMP1)								Off	Off

Table 2. Indut Configuration (DIN). Differential Reference Wode (SER/DFR Lov	t Configuration (DIN), Differential Reference Mode (SER/D	R Low
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A2	A1	A0	+REF	-REF	Y-	X+	Y+	Y-Position	X-Position	Z ₁ -Position	Z ₂ -Position	Drivers
0	0	1	Y+	Y-		+IN		Measure				Y+, Y-
0	1	1	Y+	X-		+IN				Measure		Y+, X-
1	0	0	Y+	X-	+IN						Measure	Y+, X-
1	0	1	X+	X-			+IN		Measure			X+, X-

Internal Reference

The TSC2046E has an internal 2.5-V voltage reference that can be turned on or off with the power-down control bit, PD1 (see Table 5 and Figure 3). Typically, the internal reference voltage is only used in the single-ended mode for battery monitoring, temperature measurement, and for using the auxiliary input. Optimal touch screen performance is achieved when using the differential mode. The internal reference voltage of the TSC2046E must be commanded to be off to maintain compatibility with the ADS7843. Therefore, after power-up, a write of PD1 = 0 is required to ensure the reference is off (see the Typical Characteristics for power-up time of the reference from power-down).

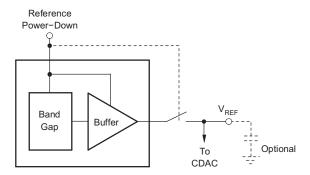


Figure 3. Simplified Diagram of the Internal Reference

Reference Input

The voltage difference between +REF and -REF (see Figure 2) sets the analog input range. The TSC2046E operates with a reference in the range of 1V to \pm V_{CC}. There are several critical items concerning the reference input and its wide voltage range. As the reference voltage is reduced, the analog voltage weight of each digital output code (referred to as LSB size) is also reduced. The LSB (least significant bit) size is equal to the reference voltage divided by 4096 in 12-bit mode. Any offset or gain error inherent in the ADC appears to increase, in terms of LSB size, as the reference voltage is reduced. For example, if the offset of a given converter is 2LSBs with a 2.5V reference, it is typically 5LSBs with a 1V reference. In each case, the actual offset of the device is the same, 1.22mV. With a lower reference voltage, more care must be taken to provide a clean layout including adequate bypassing, a clean (low-noise, low-ripple) power supply, a low-noise reference (if an external reference is used), and a low-noise input signal.

The voltage into the V_{REF} input directly drives the capacitor digital-to-analog converter (CDAC) portion of the TSC2046E. Therefore, the input current is very low (typically less than 13 μ A).

There is also a critical item regarding the reference when making measurements while the switch drivers are ON. For this discussion, it is useful to consider the basic operation of the TSC2046E (see Figure 1). This particular application shows the device being used to digitize a resistive touch screen. A measurement of the current Y-Position of the pointing device is made by connecting the X+ input to the ADC, turning on the Y+ and Y-drivers, and digitizing the voltage on X+ (Figure 4 shows a block diagram). For this measurement, the resistance in the X+ lead does not affect the conversion (it does affect the settling time, but the resistance is usually small enough that this is not a concern). However, because the resistance between Y+ and Y- is fairly low, the on-resistance of the Y drivers does make a small difference. Under the situation outlined so far, it is not possible to achieve a 0V input or a full-scale input regardless of where the pointing device is on the touch screen because some voltage is lost across the internal switches. In addition, the internal switch resistance is unlikely to track the resistance of the touch screen, providing an additional source of error.



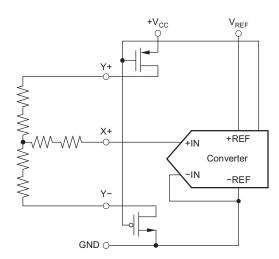


Figure 4. Simplified Diagram of Single-Ended Reference (SER/DFR High, Y Switches Enabled, X+ is Analog Input)

This situation can be remedied as shown in Figure 5. By setting the SER/DFR bit low, the +REF and -REF inputs are connected directly to Y+ and Y-, respectively, making the analog-to-digital conversion ratiometric. The result of the conversion is always a percentage of the external resistance, regardless of how it changes in relation to the on-resistance of the internal switches. Note that there is an important consideration regarding power dissipation when using the ratiometric mode of operation (see the Power Dissipation section for more details).

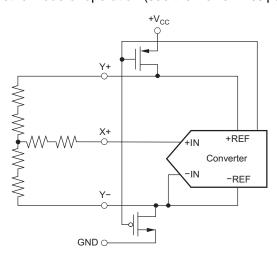


Figure 5. Simplified Diagram of Differential Reference (SER/DFR Low, Y Switches Enabled, X+ is Analog Input)

As a final note about the differential reference mode, it must be used with $+V_{CC}$ as the source of the +REF voltage and cannot be used with V_{REF} . It is possible to use a high-precision reference on V_{REF} and single-ended reference mode for measurements that do not need to be ratiometric. In some cases, it is possible to power the converter directly from a precision reference. Most references can provide enough power for the TSC2046E, but might not be able to supply enough current for the external load (such as a resistive touch screen).



Touch Screen Settling

In some applications, external capacitors may be required across the touch screen for filtering noise picked up by the touch screen (for example, noise generated by the LCD panel or backlight circuitry). These capacitors provide a low-pass filter to reduce the noise, but cause a settling time requirement when the panel is touched that typically shows up as a gain error. There are several methods for minimizing or eliminating this issue. The problem is that the input and/or reference has not settled to the final steady-state value prior to the ADC sampling the input(s) and providing the digital output. Additionally, the reference voltage may still be changing during the measurement cycle. Option 1 is to stop or slow down the TSC2046E DCLK for the required touch screen settling time. This option allows the input and reference to have stable values for the Acquire period (3 clock cycles of the TSC2046E; see Figure 9). This option works for both the single-ended and the differential modes. Option 2 is to operate the TSC2046E in the differential mode only for the touch screen measurements and command the TSC2046E to remain on (touch screen drivers ON) and not go into power-down (PD0 = 1). Several conversions are made, depending on the settling time required and the TSC2046E data rate. Once the required number of conversions have been made, the processor commands the TSC2046E to go into its power-down state on the last measurement. This process is required for X-Position, Y-Position, and Z-Position measurements. Option 3 is to operate in the 15 Clock-per-Conversion mode, which overlaps the analog-to-digital conversions and maintains the touch screen drivers on until commanded to stop by the processor (see Figure 13).

Temperature Measurement

In some applications, such as battery recharging, a measurement of ambient temperature is required. The temperature measurement technique used in the TSC2046E relies on the characteristics of a semiconductor junction operating at a fixed current level. The forward diode voltage (V_{BE}) has a well-defined characteristic versus temperature. The ambient temperature can be predicted in applications by knowing the +25°C value of the VBEvoltage and then monitoring the delta of that voltage as the temperature changes. The TSC2046E offers two modes of operation. The first mode requires calibration at a known temperature, but only requires a single reading to predict the ambient temperature. A diode is used (turned on) during this measurement cycle. The voltage across the diode is connected through the MUX for digitizing the forward bias voltage by the ADC with an address of A2 = 0, A1 = 0, and A0 = 0 (see Table 1 and Figure 6 for details). This voltage is typically 600mV at +25°C with a 20µA current through the diode. The absolute value of this diode voltage can vary by a few millivolts. However, the temperature coefficient (TC) of this voltage is very consistent at -2.1mV/°C. During the final test of the end product, the diode voltage would be stored at a known room temperature, in memory, for calibration purposes by the user. The result is an equivalent temperature measurement resolution of 0.3°C/LSB (in 12-bit mode).

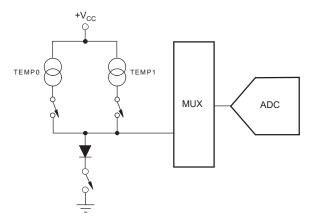


Figure 6. Temperature Measurement Functional Block Diagram



The second mode of operation does not require a test temperature calibration, but uses a two-measurement method to eliminate the need for absolute temperature calibration and for achieving 2° C accuracy. This mode requires a second conversion with an address of A2 = 1, A1 = 1, and A0 = 1, with a 91 times larger current. The voltage difference between the first and second conversion using 91 times the bias current is represented by Equation 1:

$$\Delta V = \frac{kT}{q} \times ln(N) \tag{1}$$

where:

N = the current ratio = 91

 $k = Boltzmann's constant = 1.3807 \times 10^{-23} J/K (joules/kelvin)$

q = the electron charge = 1.6022×10^{-19} C (coulombs)

T = the temperature in kelvin (K)

This method can provide improved absolute temperature measurement, but at a lower resolution of 1.6°C/LSB. The resulting equation that solves for T is:

$$T = \frac{q - \Delta V}{k \times ln(N)}$$
 (2)

where:

$$\begin{split} \Delta V &= V_{BE}(TEMP1) - V_{BE}(TEMP0) \text{ (in mV)} \\ \therefore & T = 2.573 \cdot \Delta V \text{ (in K)} \\ \text{or } T = 2.573 \cdot \Delta V - 273 \text{ (in °C)} \end{split}$$

NOTE

The bias current for each diode temperature measurement is only on for three clock cycles (during the acquisition mode) and, therefore, does not add any noticeable increase in power, especially if the temperature measurement only occurs occasionally.

Battery Measurement

An added feature of the TSC2046E is the ability to monitor the battery voltage on the other side of the voltage regulator (dc/dc converter), as shown in Figure 7. The battery voltage can vary from 0V to 6V, while maintaining the voltage to the TSC2046E at 2.7V, 3.3V, etc. The input voltage (VBAT) is divided down by four so that a 5.5V battery voltage is represented as 1.375V to the ADC. This design simplifies the multiplexer and control logic. In order to minimize the power consumption, the divider is only on during the sampling period when A2 = 0, A1 = 1, and A0 = 0 (see Table 1 for the relationship between the control bits and configuration of the TSC2046E).

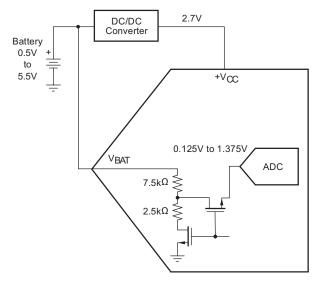


Figure 7. Battery Measurement Functional Block Diagram

Pressure Measurement

Measuring touch pressure can also be done with the TSC2046E. To determine pen or finger touch, the pressure of the touch needs to be determined. Generally, it is not necessary to have very high performance for this test; therefore, the 8-bit resolution mode is recommended (however, calculations shown here are in the 12-bit resolution mode). There are several different ways of performing this measurement. The TSC2046E supports two methods. The first method requires knowing the X-plate resistance, measurement of the X-Position, and two additional cross panel measurements (Z1 and Z2) of the touch screen, as shown in Figure 8. Using Equation 3 calculates the touch resistance:

$$R_{\text{TOUCH}} = R_{\text{X-Plate}} \times \frac{\text{X-Position}}{4096} \left(\frac{Z_2}{Z_1} - 1 \right)$$
(3)

The second method requires knowing both the X-Plate and Y-Plate resistance, measurement of X-Position and Y-Position, and Z1. Equation 4 calculates the touch resistance using the second method:

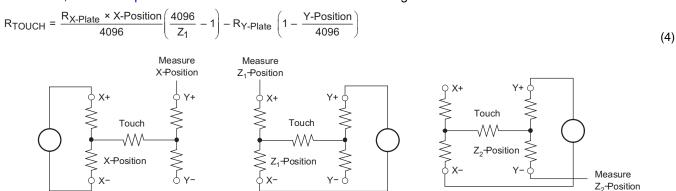


Figure 8. Pressure Measurement Block Diagram

Digital Interface

See Figure 9 for the typical operation of the TSC2046E digital interface. This diagram assumes that the source of the digital signals is a microcontroller or digital signal processor with a basic serial interface. Each communication between the processor and the converter, such as SPI, SSI, or Microwire™ synchronous serial interface, consists of eight clock cycles. One complete conversion can be accomplished with three serial communications for a total of 24 clock cycles on the DCLK input.

Control Byte

The control byte (on DIN), as shown in Table 3, provides the start conversion, addressing, ADC resolution, configuration, and power-down of the TSC2046E. Figure 9, Table 3 and Table 4 give detailed information regarding the order and description of these control bits within the control byte.

Initiate START—The first bit, the S bit, must always be high and initiates the start of the control byte. The TSC2046E ignores inputs on the DIN pin until the start bit is detected.

Addressing—The next three bits (A2, A1, and A0) select the active input channel(s) of the input multiplexer (see Table 1, Table 2, and Figure 2), touch screen drivers, and the reference inputs.

MODE—The mode bit sets the resolution of the ADC. With this bit low, the next conversion has 12-bit resolution, whereas with this bit high, the next conversion has 8-bit resolution.

SER/DFR—The SER/DFR bit controls the reference mode, either single-ended (high) or differential (low). The differential mode is also referred to as the ratiometric conversion mode and is preferred for X-Position, Y-Position, and Pressure-Touch measurements for optimum performance. The reference is derived from the voltage at the switch drivers, which is almost the same as the voltage to the touch screen. In this case, a reference voltage is not needed as the reference voltage to the ADC is the voltage across the touch screen. In the single-ended mode, the converter reference voltage is always the difference between the V_{REF} and GND pins (see Table 1 and Table 2, and Figure 2 through Figure 5, for further information).

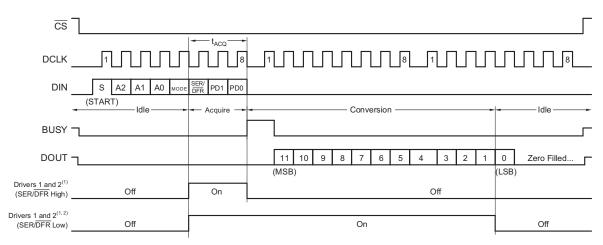
Table 3. Order of the Control Bits in the Control Byte

BIT 7 (MSB)	BIT 6	BIT 5	BIT 4	BIT 3	BIT 2	BIT 1	BIT 0 (LSB)
S	A2	A1	A0	MODE	SER/DFR	PD1	PD0

Table 4. Descriptions of the Control Bits within the Control Byte

BIT	NAME	DESCRIPTION
7	S	Start bit. Control byte starts with first high bit on DIN. A new control byte can start every 15th clock cycle in 12-bit conversion mode or every 11th clock cycle in 8-bit conversion mode (see Figure 13).
6-4	A2-A0	Channel Select bits. Along with the SER/DFR bit, these bits control the setting of the multiplexer input, touch driver switches, and reference inputs (see Table 1 and Figure 13).
3	MODE	12-Bit/8-Bit Conversion Select bit. This bit controls the number of bits for the next conversion: 12-bits (low) or 8-bits (high).
2	SER/DFR	Single-Ended/Differential Reference Select bit. Along with bits A2-A0, this bit controls the setting of the multiplexer input, touch driver switches, and reference inputs (see Table 1 and Table 2).
1-0	PD1-PD0	Power-Down Mode Select bits. See Table 5 for details.

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NOTES: (1) For Y-Position, Driver 1 is on X+ is selected, and Driver 2 is off. For X-Position, Driver 1 is off, Y+ is selected, and Driver 2 is on. Y- will turn on when power-down mode is entered and PD0 = 0.

(2) Drivers will remain on if PD0 = 1 (no power down) until selected input channel, reference mode, or power-down mode is changed, or CS is high.

Figure 9. Conversion Timing, 24 Clocks-per-Conversion, 8-Bit Bus Interface No DCLK Delay Required With Dedicated Serial Port

If X-Position, Y-Position, and Pressure-Touch are measured in the single-ended mode, an external reference voltage is needed. The TSC2046E must also be powered from the external reference. Caution should be observed when using the single-ended mode such that the input voltage to the ADC does not exceed the internal reference voltage, especially if the supply voltage is greater than 2.7V.

NOTE

The differential mode can only be used for X-Position, Y-Position, and Pressure-Touch measurements. All other measurements require the single-ended mode.

PD0 and **PD1**—Table 5 describes the power-down and the internal reference voltage configurations. The internal reference voltage can be turned on or off independently of the ADC. This feature can allow extra time for the internal reference voltage to settle to the final value prior to making a conversion. Make sure to also allow this extra wake-up time if the internal reference is powered down. The ADC requires no wake-up time and can be instantaneously used. Also note that the status of the internal reference power-down is latched into the part (internally) with BUSY going high. In order to turn the reference off, an additional write to the TSC2046E is required after the channel has been converted.

Table 5. Power-Down and Internal Reference Selection

PD1	PD0	PENIRQ	DESCRIPTION
0	0	Enabled	Power-Down Between Conversions. When each conversion is finished, the converter enters a low-power mode. At the start of the next conversion, the device instantly powers up to full power. There is no need for additional delays to ensure full operation, and the very first conversion is valid. The Y-switch is on when in power-down.
0	1	Disabled	Reference is off and ADC is on.
1	0	Enabled	Reference is on and ADC is off.
1	1	Disabled	Device is always powered. Reference is on and ADC is on.

PENIRQ Output

The pen-interrupt output function is shown in Figure 10. While in power-down mode with PD0 = 0, the Y-driver is on and connects the Y-plane of the touch screen to GND. The PENIRQ output is connected to the X+ input through two transmission gates. When the screen is touched, the X+ input is pulled to ground through the touch screen.



In most of the TSC2046E models, the internal pullup resistor value is nominally $50k\Omega$, but this value may vary between $36k\Omega$ and $67k\Omega$ given process and temperature variations. In order to assure a logic low of $0.35~(+V_{CC})$ is presented to the \overline{PENIRQ} circuitry, the total resistance between the X+ and Y- terminals must be less than $21k\Omega$.

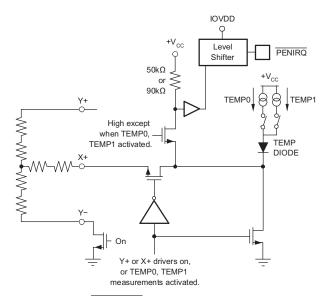


Figure 10. PENIRQ Functional Block Diagram

The -90 version of the TSC2046E uses a nominal $90k\Omega$ pullup resistor that allows the total resistance between the X+ and Y- terminals to be as high as $30k\Omega$. Note that the higher pullup resistance causes a slower response time of the PENIRQ to a screen touch, so user software should take this into account.

The PENIRQ output goes low due to the current path through the touch screen to ground, initiating an interrupt to the processor. During the measurement cycle for X-, Y-, and Z-Position, the X+ input is disconnected from the PENIRQ internal pull-up resistor. This disconnection is done to eliminate any leakage current from the internal pull-up resistor through the touch screen, thus causing no errors.

Furthermore, the PENIRQ output is disabled and low during the measurement cycle for X-, Y-, and Z-Position. The PENIRQ output is disabled and high during the measurement cycle for battery monitor, auxiliary input, and chip temperature. If the last control byte written to the TSC2046E contains PD0 = 1, the pen-interrupt output function is disabled and is not able to detect when the screen is touched. In order to re-enable the pen-interrupt output function under these circumstances, a control byte needs to be written to the TSC2046E with PD0 = 0. If the last control byte written to the TSC2046E contains PD0 = 0, the pen-interrupt output function is enabled at the end of the conversion. The end of the conversion occurs on the falling edge of DCLK after bit 1 of the converted data is clocked out of the TSC2046E.

It is recommended that the processor mask the interrupt that $\overline{\text{PENIRQ}}$ is associated with whenever the processor sends a control byte to the TSC2046E. This masking prevents false triggering of interrupts when the PENIRQ output is disabled in the cases discussed in this section.

16 Clocks-per-Conversion

The control bits for conversion n+1 can be overlapped with conversion n to allow for a conversion every 16 clock cycles, as shown in Figure 11. This figure also shows possible serial communication occurring with other serial peripherals between each byte transfer from the processor to the converter. (16 clocks cycles are possible, provided that each conversion completes within 1.6ms of starting. Otherwise, the signal that is captured on the input sample-and-hold may droop enough to affect the conversion result.) Note that the TSC2046E is fully powered while other serial communications are taking place during a conversion.

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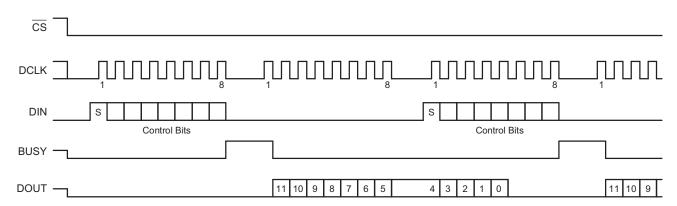


Figure 11. Conversion Timing, 16 Clocks-per-Conversion, 8-Bit Bus Interface No DCLK Delay Required With Dedicated Serial Port

Digital Timing

Figure 9, Figure 12, and Table 6 provide detailed timing for the digital interface of the TSC2046E.

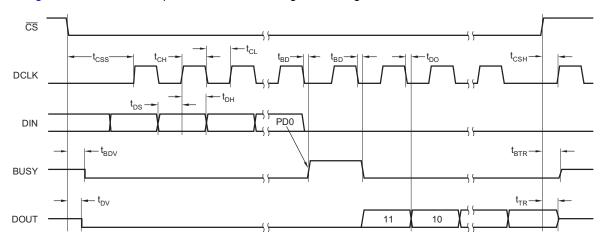


Figure 12. Detailed Timing Diagram

Table 6. Timing Specifications⁽¹⁾

SYMBOL	DESCRIPTION	MIN	TYP MAX	UNIT
t _{ACQ}	Acquisition Time	1.5		μs
t _{DS}	DIN Valid Prior to DCLK Rising	100		ns
t _{DH}	DIN Hold After DCLK High	50		ns
t_{DO}	DCLK Falling to DOUT Valid		200	ns
t _{DV}	CS Falling to DOUT Enabled		200	ns
t _{TR}	CS Rising to DOUT Disabled		200	ns
t _{CSS}	CS Falling to First DCLK Rising	100		ns
t _{CSH}	CS Rising to DCLK Ignored	10		ns
t _{CH}	DCLK High	200		ns
t _{CL}	DCLK Low	200		ns
t _{BD}	DCLK Falling to BUSY Rising/Falling		200	ns
t _{BDV}	CS Falling to BUSY Enabled		200	ns
t _{BTR}	CS Rising to BUSY Disabled		200	ns

⁽¹⁾ $T_A = -40$ °C to +125°C, + $V_{CC} = 2.7V$, + $V_{CC} \ge IOVDD \ge 1.5V$, $C_{LOAD} = 50$ pF



15 Clocks-per-Conversion

Figure 13 provides the fastest way to clock the TSC2046E. This method does not work with the serial interface of most microcontrollers and digital signal processors, as they are generally not capable of providing 15 clock cycles per serial transfer. However, this method can be used with field-programmable gate arrays (FPGAs) or application- specific integrated circuits (ASICs). Note that this effectively increases the maximum conversion rate of the converter beyond the values given in the specification tables, which assume 16 clock cycles per conversion.

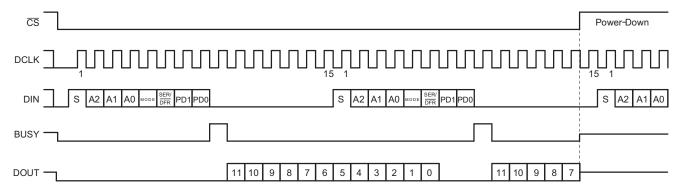
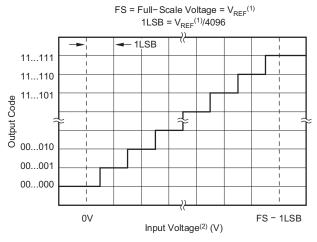


Figure 13. Maximum Conversion Rate, 15 Clocks-per-Conversion

Data Format

The TSC2046E output data is in Straight Binary format, as shown in Figure 14. This figure shows the ideal output code for the given input voltage and does not include the effects of offset, gain, or noise.



NOTES: (1) Reference voltage at converter: +REF - (-REF); see Figure 2.

(2) Input voltage at converter, after multiplexer: +IN - (-IN); see Figure 2.

Figure 14. Ideal Input Voltages and Output Codes

8-Bit Conversion

The TSC2046E provides an 8-bit conversion mode that can be used when faster throughput is needed and the digital result is not as critical. By switching to the 8-bit mode, a conversion is complete four clock cycles earlier. Not only does this shorten each conversion by four bits (25% faster throughput), but each conversion can actually occur at a faster clock rate. This faster rate occurs because the internal settling time of the TSC2046E is not as critical—settling to better than 8 bits is all that is needed. The clock rate can be as much as 50% faster. The faster clock rate and fewer clock cycles combine to provide a 2x increase in conversion rate.

20 Su

Power Dissipation

There are two major power modes for the TSC2046E: full-power (PD0 = 1) and auto power-down (PD0 = 0). When operating at full speed and 16 clocks-per-conversion (see Figure 11), the TSC2046E spends most of the time acquiring or converting. There is little time for auto power-down, assuming that this mode is active. Therefore, the difference between full-power mode and auto power-down is negligible. If the conversion rate is decreased by slowing the frequency of the DCLK input, the two modes remain approximately equal. However, if the DCLK frequency is kept at the maximum rate during a conversion but conversions are done less often, the difference between the two modes is dramatic.

Figure 15 shows the difference between reducing the DCLK frequency (scaling DCLK to match the conversion rate) or maintaining DCLK at the highest frequency and reducing the number of conversions per second. In the latter case, the converter spends an increasing percentage of time in power-down mode (assuming the auto power-down mode is active).

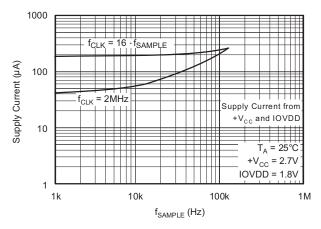


Figure 15. Supply Current vs Directly Scaling the Frequency of DCLK with Sample Rate or Maintaining DCLK at the Maximum Possible Frequency

Another important consideration for power dissipation is the reference mode of the converter. In the single-ended reference mode, the touch panel drivers are ON only when the analog input voltage is being acquired (see Figure 9 and Table 1). The external device (for example, a resistive touch screen), therefore, is only powered during the acquisition period. In the differential reference mode, the external device must be powered throughout the acquisition and conversion periods (see Figure 9). If the conversion rate is high, it could substantially increase power dissipation.

 $\overline{\text{CS}}$ also puts the TSC2046E into power-down mode. When $\overline{\text{CS}}$ goes high, the TSC2046E immediately goes into power-down mode and does not complete the current conversion. The internal reference, however, does not turn off with $\overline{\text{CS}}$ going high. To turn the reference off, an additional write is required before $\overline{\text{CS}}$ goes high (PD1 = 0).

When the TSC2046E first powers up, the device draws about $20\mu\text{A}$ of current until a control byte is written to it with $\underline{PD0} = 0$ to put it into power-down mode. This current draw can be avoided if the TSC2046E is powered up with $\overline{CS} = 0$ and DCLK = IOVDD.



Layout

The following layout suggestions provide the most optimum performance from the TSC2046E. Many portable applications, however, have conflicting requirements concerning power, cost, size, and weight. In general, most portable devices have fairly clean power and grounds because most of the internal components are very low power. This situation means less bypassing for the converter power and less concern regarding grounding. Still, each situation is unique and the following suggestions should be reviewed carefully.

For optimum performance, care should be taken with the physical layout of the TSC2046E circuitry. The basic SAR architecture is sensitive to glitches or sudden changes on the power supply, reference, ground connections, and digital inputs that occur just prior to latching the output of the analog comparator. Therefore, during any single conversion for an n-bit SAR converter, there are n windows in which large external transient voltages can easily affect the conversion result. Such glitches can originate from switching power supplies, nearby digital logic, and high-power devices. The degree of error in the digital output depends on the reference voltage, layout, and the exact timing of the external event. The error can change if the external event changes in time with respect to the DCLK input.

Because of the SAR architecture sensitvity, power to the TSC2046E should be clean and well bypassed. A $0.1\mu F$ ceramic bypass capacitor should be placed as close to the device as possible. A $1\mu F$ to $10\mu F$ capacitor may also be needed if the impedance of the connection between $+V_{CC}$ or IOVDD and the power supplies is high. Low-leakage capacitors should be used to minimize power dissipation through the bypass capacitors when the TSC2046E is in power-down mode.

A bypass capacitor is generally not needed on the V_{REF} pin because the internal reference is buffered by an internal op amp. If an external reference voltage originates from an op amp, make sure that it can drive any bypass capacitor that is used without oscillation.

The TSC2046E architecture offers no inherent rejection of noise or voltage variation in regards to using an external reference input. This is of particular concern when the reference input is tied to the power supply. Any noise and ripple from the supply appears directly in the digital results. Whereas high-frequency noise can be filtered out, voltage variation bacause of line frequency (50Hz or 60Hz) can be difficult to remove.

The GND pin must be connected to a clean ground point. In many cases, this is the analog ground. Avoid connections which are too near the grounding point of a microcontroller or digital signal processor. If needed, run a ground trace directly from the converter to the power-supply entry or battery connection point. The ideal layout includes an analog ground plane dedicated to the converter and associated analog circuitry.

In the specific case of use with a resistive touch screen, care should be taken with the connection between the converter and the touch screen. Although resistive touch screens have fairly low resistance, the interconnection should be as short and robust as possible. Longer connections are a source of error, much like the on-resistance of the internal switches. Likewise, loose connections can be a source of error when the contact resistance changes with flexing or vibrations.

As indicated previously, noise can be a major source of error in touch screen applications (such as in applications that require a backlit LCD panel). This EMI noise can be coupled through the LCD panel to the touch screen and cause flickering of the converted data. Several things can be done to reduce this error; for instance, using a touch screen with a bottom-side metal layer connected to ground to shunt the majority of noise to ground. Additionally, filtering capacitors from Y+, Y-, X+, and X- pins to ground can also help. Caution should be observed under these circumstances for settling time of the touch screen, especially operating in the single-ended mode and at high data rates.

16-Jul-2010

PACKAGING INFORMATION

Orderable Device	Status ⁽¹⁾	Package Type	Package Drawing	Pins	Package Qty	Eco Plan ⁽²⁾	Lead/ Ball Finish	MSL Peak Temp ⁽³⁾	Samples (Requires Login)
TSC2046EQPWRQ1	ACTIVE	TSSOP	PW	16	2000	Green (RoHS & no Sb/Br)	CU NIPDAU	Level-1-260C-UNLIM	Purchase Samples

(1) The marketing status values are defined as follows:

ACTIVE: Product device recommended for new designs.

LIFEBUY: TI has announced that the device will be discontinued, and a lifetime-buy period is in effect.

NRND: Not recommended for new designs. Device is in production to support existing customers, but TI does not recommend using this part in a new design.

PREVIEW: Device has been announced but is not in production. Samples may or may not be available.

OBSOLETE: TI has discontinued the production of the device.

(2) Eco Plan - The planned eco-friendly classification: Pb-Free (RoHS), Pb-Free (RoHS Exempt), or Green (RoHS & no Sb/Br) - please check http://www.ti.com/productcontent for the latest availability information and additional product content details.

TBD: The Pb-Free/Green conversion plan has not been defined.

Pb-Free (RoHS): TI's terms "Lead-Free" or "Pb-Free" mean semiconductor products that are compatible with the current RoHS requirements for all 6 substances, including the requirement that lead not exceed 0.1% by weight in homogeneous materials. Where designed to be soldered at high temperatures, TI Pb-Free products are suitable for use in specified lead-free processes.

Pb-Free (RoHS Exempt): This component has a RoHS exemption for either 1) lead-based flip-chip solder bumps used between the die and package, or 2) lead-based die adhesive used between the die and leadframe. The component is otherwise considered Pb-Free (RoHS compatible) as defined above.

Green (RoHS & no Sb/Br): TI defines "Green" to mean Pb-Free (RoHS compatible), and free of Bromine (Br) and Antimony (Sb) based flame retardants (Br or Sb do not exceed 0.1% by weight in homogeneous material)

(3) MSL, Peak Temp. -- The Moisture Sensitivity Level rating according to the JEDEC industry standard classifications, and peak solder temperature.

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NOTE: Qualified Version Definitions:

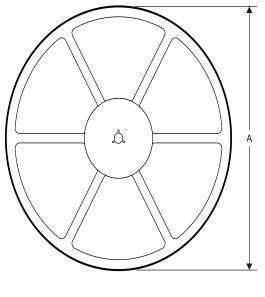
Catalog - TI's standard catalog product

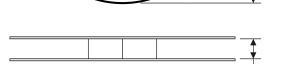
PACKAGE MATERIALS INFORMATION

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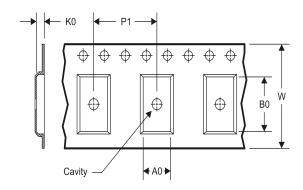
TAPE AND REEL INFORMATION

REEL DIMENSIONS





TAPE DIMENSIONS



A0	Dimension designed to accommodate the component width
В0	Dimension designed to accommodate the component length
K0	Dimension designed to accommodate the component thickness
W	Overall width of the carrier tape
P1	Pitch between successive cavity centers

TAPE AND REEL INFORMATION

*All dimensions are nominal

Device	Package Type	Package Drawing		SPQ	Reel Diameter (mm)	Reel Width W1 (mm)	A0 (mm)	B0 (mm)	K0 (mm)	P1 (mm)	W (mm)	Pin1 Quadrant
TSC2046EQPWRQ1	TSSOP	PW	16	2000	330.0	12.4	6.9	5.6	1.6	8.0	12.0	Q1

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*All dimensions are nominal

Device	Package Type	Package Drawing	Pins	SPQ	Length (mm)	Width (mm)	Height (mm)
TSC2046EQPWRQ1	TSSOP	PW	16	2000	367.0	367.0	35.0

PW (R-PDSO-G16)

PLASTIC SMALL OUTLINE



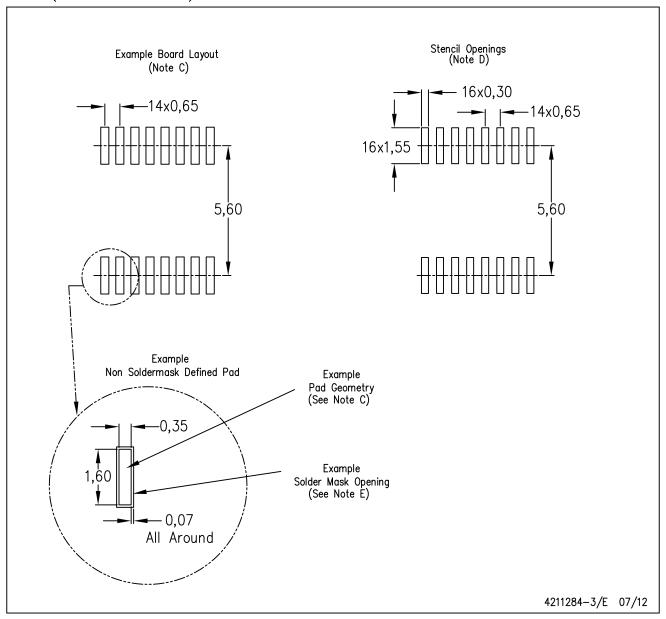
NOTES:

- A. All linear dimensions are in millimeters. Dimensioning and tolerancing per ASME Y14.5M—1994.
- B. This drawing is subject to change without notice.
- Body length does not include mold flash, protrusions, or gate burrs. Mold flash, protrusions, or gate burrs shall not exceed 0,15 each side.
- Body width does not include interlead flash. Interlead flash shall not exceed 0,25 each side.
- E. Falls within JEDEC MO-153



PW (R-PDSO-G16)

PLASTIC SMALL OUTLINE



NOTES:

- A. All linear dimensions are in millimeters.
- B. This drawing is subject to change without notice.
- C. Publication IPC-7351 is recommended for alternate designs.
- D. Laser cutting apertures with trapezoidal walls and also rounding corners will offer better paste release. Customers should contact their board assembly site for stencil design recommendations. Refer to IPC-7525 for other stencil recommendations.
- E. Customers should contact their board fabrication site for solder mask tolerances between and around signal pads.



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